



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Kittl et al. Art Unit: 2829
Serial No.: 10/023,825 Examiner: Kobert, R.
Filing Date: 12/19/2001 Docket No.: TI-23892
Customer No.: 23494 Conf. No.: 8239
Title: METHOD TO IMPROVE SILICIDE FORMATION ON POLYSILICON

SUPPLEMENTAL DECLARATION

Commissioner of Patents
P. O. Box 1450
Alexandria, VA 22313-1450


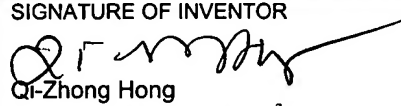
Sir:

I (We), Jorge A. Kittl and Qi-Zhong Hong, as joint inventors named in the application for letters patent for an improvement in, Serial No. 10/023,825, filed in the United States Patent and Trademark Office on or about the 19th day of December, 2001, declare that I have reviewed and understand the subject matter of the following amendment(s):

Amendment 1.111 filed 1/20/2004
Amendment 1.111 filed 3/17/2004

that said subject matter, including the claims as amended, was part of our invention, and was invented before the filing of the original application, above identified, for such invention; and that I acknowledge my duty to disclose information of which I am aware which is material to the patentability of this application in accordance with Title 37, Code of Federal Regulations, §1.56.

I further declare that all statements herein made of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

SIGNATURE OF INVENTOR  Jorge A. Kittl	SIGNATURE OF INVENTOR  Qi-Zhong Hong	SIGNATURE OF INVENTOR
DATE 6/16/04	DATE 6/21/04	DATE